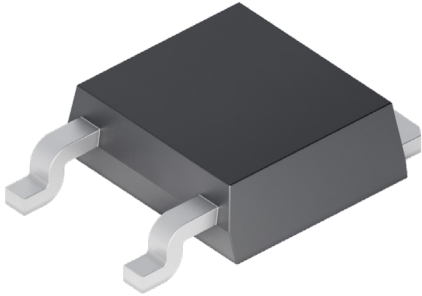


DCK10I1200UZ

1200 V, 10 A SiC Schottky Diode

RoHS

HF



Features

- Maximum virtual junction temperature of 175 °C
- High surge current capacity
- Extremely fast reverse recovery time
- High-frequency operation
- Temperature independent switching behavior
- Positive temperature coefficient on V_F

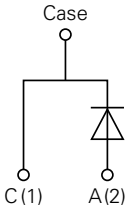
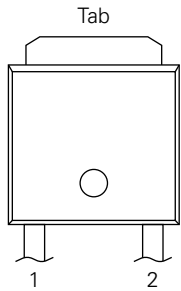
Applications

- Solar power boost
- Inverter free wheeling diodes
- AC/DC converters
- Switch mode power supplies

Product Summary

Characteristic	Value	Unit
V_{RRM}	1200	V
$I_F (T_c = 158\text{ °C})$	10	A
Q_c	59	nC

Pinout Diagram TO-252-2L



1: Cathode; **2:** Anode; **Tab:** Case

Maximum Ratings ($T_c = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)

Symbol	Characteristic	Conditions	Value	Unit
V_{RRM}	Repetitive peak reverse voltage	–	1200	V
V_{DC}	DC blocking voltage	–	1200	V
I_F	Continuous forward current	–	$T_c = 25\text{ }^{\circ}\text{C}$	A
			$T_c = 135\text{ }^{\circ}\text{C}$	
			$T_c = 158\text{ }^{\circ}\text{C}$	
I_{FSM}	Non-repetitive surge forward current	Sine halfwave @ $T_c = 25\text{ }^{\circ}\text{C}$, $t_p = 10\text{ ms}$	90	A
I_{FRM}	Repetitive peak forward current	Frequency = 0.1 Hz, 100 cycles sine halfwave @ $T_c = 25\text{ }^{\circ}\text{C}$, $t_p = 10\text{ ms}$	72	A
P_{tot}	Total power dissipation	–	$T_c = 25\text{ }^{\circ}\text{C}$	W
			$T_c = 150\text{ }^{\circ}\text{C}$	
I^2t	I^2t	$T_c = 25\text{ }^{\circ}\text{C}$, $t_p = 10\text{ ms}$	40.5	A ² s
T_{vj}	Virtual operating junction temperature range	–	–55 to 175	$^{\circ}\text{C}$
T_{stg}	Storage temperature range	–	–55 to 175	$^{\circ}\text{C}$

Note: Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Thermal Characteristics

Symbol	Characteristic	Value			Unit
		Min.	Typ.	Max.	
$R_{th(j-c)}$	Thermal resistance, junction to case ^{Fig.7}	–	0.80	–	K/W

Electrical Characteristics ($T_{vj} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)

Symbol	Characteristic	Conditions	Value			Unit
			Min.	Typ.	Max.	
V_F	Forward voltage ^{Fig.1}	$I_F = 10\text{ A}$	$T_{vj} = 25\text{ }^{\circ}\text{C}$	–	1.48	V
			$T_{vj} = 175\text{ }^{\circ}\text{C}$	–	2.1	
I_R	Reverse current ^{Fig.2}	$V_R = 1200\text{ V}$	$T_{vj} = 25\text{ }^{\circ}\text{C}$	–	1	μA
			$T_{vj} = 175\text{ }^{\circ}\text{C}$	–	10	
C	Total capacitance ^{Fig.3}	$V_R = 1\text{ V}$, $f = 1\text{ MHz}$	–	595	–	pF
		$V_R = 400\text{ V}$, $f = 1\text{ MHz}$	–	58	–	
		$V_R = 800\text{ V}$, $f = 1\text{ MHz}$	–	42	–	
Q_c	Total capacitive charge ^{Fig.4}	$V_R = 800\text{ V}$, $T_{vj} = 25\text{ }^{\circ}\text{C}$, $Q_c = \int_0^{VR} C(V)dV$	–	59	–	nC
E_c	Capacitance stored energy ^{Fig.5}	$V_R = 800\text{ V}$, $T_{vj} = 25\text{ }^{\circ}\text{C}$, $E_c = \int_0^{VR} C(V) \cdot VdV$	–	17.1	–	μJ

Characteristic Curves

Fig. 1. Typical Forward Characteristics

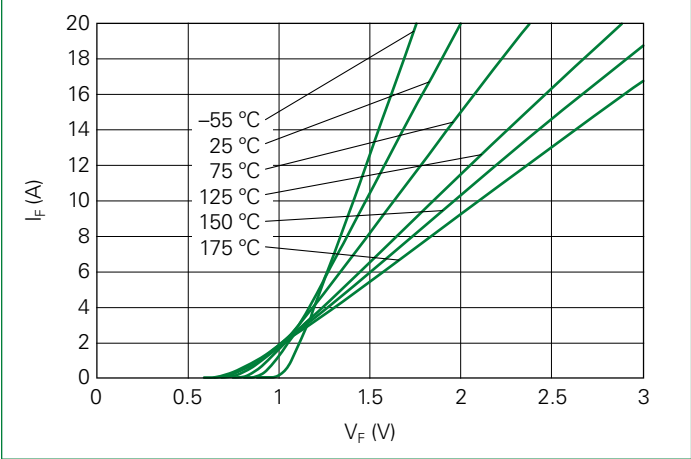


Fig. 2. Typical Reverse Characteristics

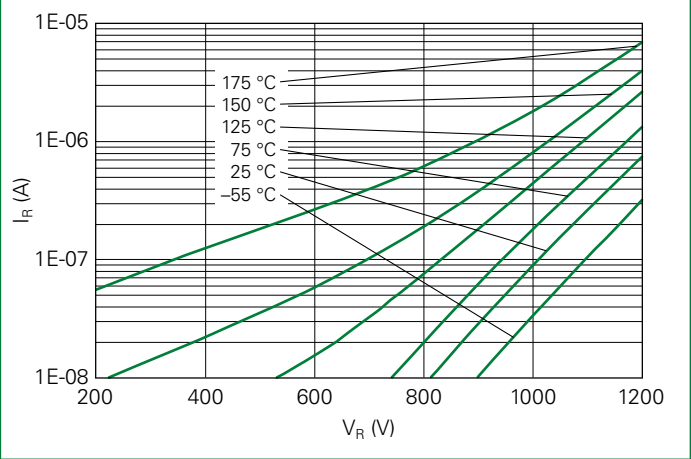


Fig. 3. Capacitance vs. Reverse Voltage

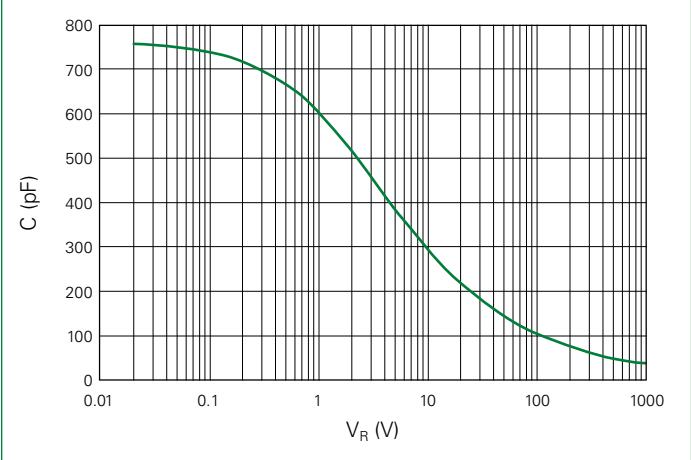


Fig. 4. Total Capacitive Charge vs. Reverse Voltage

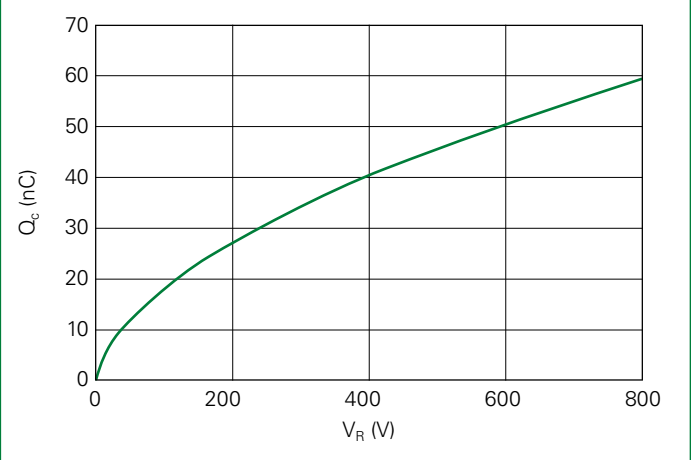


Fig. 5. Capacitance Stored Energy

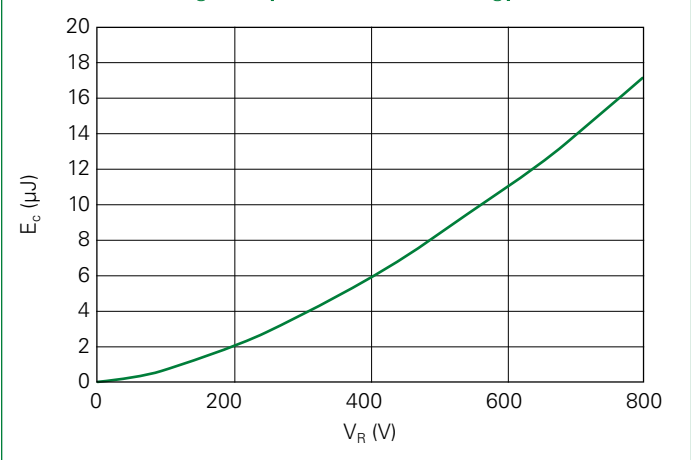
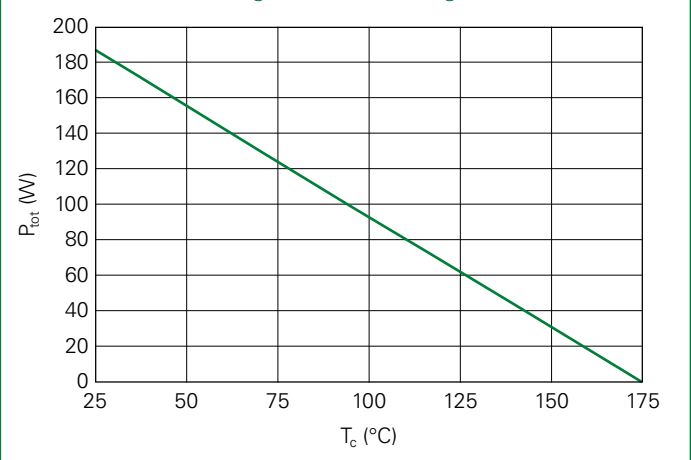
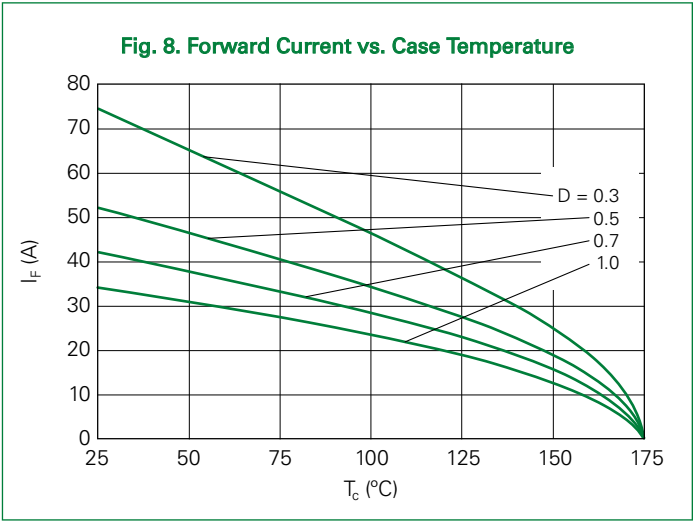
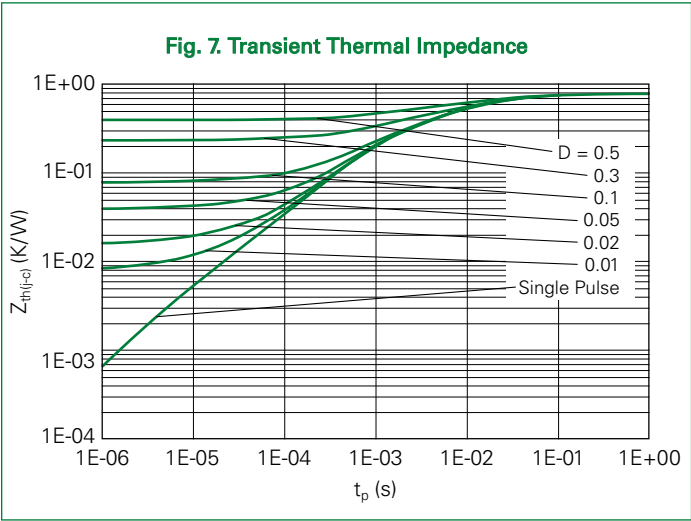
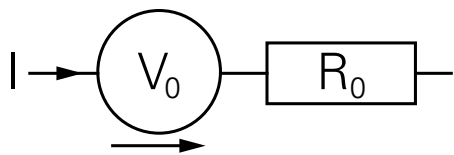


Fig. 6. Power Derating





Diode V_F Model for Simulation



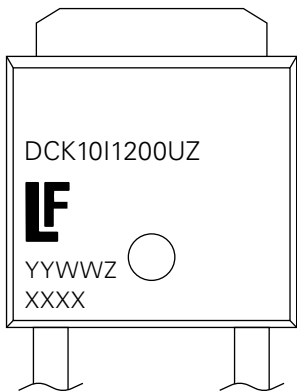
$$V_F(T_{vj}) = V_0 + I R_0$$

$$V_0 = 3 \times 10^{-9} \cdot T_{vj}^2 - 0.0012 \cdot T_{vj} + 0.9762$$

$$R_0 = 1 \times 10^{-6} \cdot T_{vj}^2 + 0.0003 \cdot T_{vj} + 0.0464$$

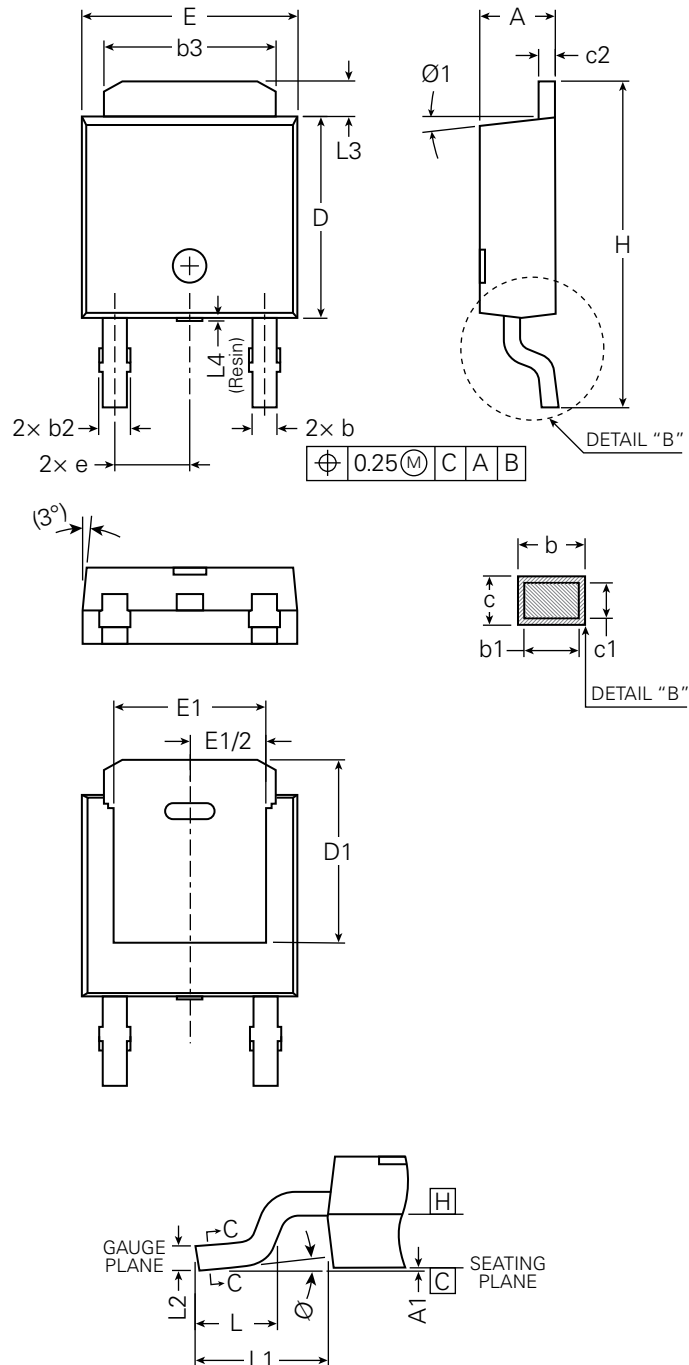
- Notes**
- T_{vj} is the virtual junction temperature in °C
 - Range valid from 25 °C to 175 °C
 - Model represents performance of a typical chart

Part Number and Marking



- DCK10I1200UZ = Part Material Number
- YY = Year
- WW = Work Week
- Z = Assembly Location
- XXXX = Lot Traceability

Part Outline Drawing TO-252-2L

**Note:**

1. Heat sink side flash is max. 0.8 mm.
2. Radius on terminal is optional.
3. Subject to change without notice.

Disclaimer Notice

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Symbol	Inches			Millimeters		
	Min.	Typical	Max.	Min.	Typical	Max
A	0.089	—	0.094	2.18	—	2.39
A1	0	—	0.005	0.00	—	0.13
b	0.026	—	0.035	0.65	—	0.89
b1	0.025	—	0.033	0.64	—	0.84
b2	0.030	—	0.044	0.76	—	1.13
b3	0.195	—	0.215	4.95	—	5.46
c	0.018	—	0.024	0.46	—	0.61
c1	0.016	—	0.022	0.41	—	0.56
c2	0.018	—	0.024	0.46	—	0.60
D	0.235	—	0.250	5.97	—	6.35
D1	0.205	—	0.224	5.21	—	5.70
E	0.250	—	0.265	6.35	—	6.73
E1	0.170	—	0.189	4.32	—	4.80
e	0.090			2.29 BSC		
H	0.391	—	0.407	9.94	—	10.34
L	0.059	—	0.070	1.50	—	1.78
L1	0.108 REF			2.74 REF		
L2	0.020 BSC			0.51 BSC		
L3	0.035	—	0.050	0.89	—	1.27
L4	0.00	—	0.020	0.00	—	0.50
Ø	0°	—	10°	0°	—	10°
Ø1	0°	—	15°	0°	—	15°



Part of:

